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Efficiency vs. stability: dopant-free hole transporting materials towards stabilized perovskite solar cells

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In the last decade, perovskite solar cells have been considered a promising and burgeoning technology for solar energy conversion with a power conversion efficiency currently exceeding 24%. However, although perovskite solar cells have achieved high power conversion efficiency, there are still several challenges limiting their industrial realization. The actual bottleneck for real uptake in the market still remains the cost-ineffective components and instability, to which doping-induced degradation of charge selective layers may contribute significantly. This article overviews the highest performance molecular and polymeric doped and dopant-free HTMs, showing how small changes in the molecular structure such as different atoms and different functional groups and changes in substitution positions or the length of the π -conjugated systems can affect photovoltaic performance and long-term stability of perovskite solar cells.

Introduction

Research on renewable energy is moving to the forefront and becoming indisputably relevant to the future security of energy needs. Among various renewable energy technologies, solar energy is an incredibly abundant and extremely clean source which has remained underexploited to date. Efficient and inexpensive energy conversion using solar cells is vital for global

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transition to a low-carbon society. Instead of the costly production of crystalline silicon, perovskite materials, which are inexpensive and abundant, are obtained by a relatively very simple synthesis process and are coated by conventional solution processing techniques.

The era of perovskite solar cells began only in 2009 with 3.8% PCE achieved by Miyasaka and his colleagues. Perovskite-based solar cells have rapidly became the hottest topic in photovoltaics due to their unique optical and electrical properties. Pioneering studies on the design of conventional perovskite solar cells have been reported in 2012 by Kim $et\ al.^2$ and Lee $et\ al.^3$ The efficiency of the perovskite solar cells has increased to 9.7% due to the dramatic improvement by utilizing spiro-MeOTAD as the hole transport material and mesoporous TiO₂ as the



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electron transport material resulting in a solid-state mesosuperstructured perovskite solar cell. This golden step has triggered the start of intensive studies of perovskite solar cells. The fast development of device engineering and perovskite composition has allowed improvement of current solar cells with over 24% power conversion efficiency certified by the NREL. In addition to improvement in the device performance, surpassing that of commercialized crystal semiconductors and other thin-film photovoltaic systems, the cost-effectiveness of materials and solution processed perovskite manufacturing makes perovskite solar cell technology inevitable.

The organic-inorganic hybrid perovskite structure has crystals with general stoichiometry ABX3 and ideally has a cubic symmetry configuration wherein the A site is a monovalent organic methylammonium (CH₃NH₃⁺, MA⁺), formamidinium (NH₂=CH₃NH₂⁺, FA⁺) or inorganic cation (Cs⁺ or Rb⁺), B is a divalent metal cation (Pb2+, Sn2+, or Ge2+) and X stands for a halide anion (I⁻, Br⁻, or Cl⁻). Although pioneering work in perovskite structures was conducted on methylammonium lead triiodide (CH3NH3PbI3) due to its excellent optoelectronic properties such as its broad absorption spectrum, high absorption coefficient,1 high charge carrier mobility,6 low exciton binding energy,7 and long electron and hole diffusion length,8 current research demonstrates that an increase in efficiency and stability of the perovskite-based solar cells is possible by combining more complex multi-cation and mixedanion compositions of the perovskite absorber layer.

Although perovskite solar cells have achieved high power conversion efficiency, there are still several challenges limiting their industrial realization. Long-term stability is one of the important issues to be resolved. The perovskite layer is prone to rapid decomposition when the device is exposed to high temperature,9 humidity,10 oxygen,11 and full solar illumination.12 The degradation mechanism of methylammonium lead iodide in the presence of water reveals that the perovskite crystals easily decompose and are converted into the precursor



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from 2014 to 2018. According to the Web of Science in 2016, Nazeeruddin is the 5th most cited chemist in the world and was one of the 19 scientists identified by Thomson Reuters as the World's Most Influential Scientific Minds in 2015 (from all scientific domains).

PbI2 with irreversible degradation; this effect is even more pronounced in the presence of heat, an electrical field or UV light.13 On the other hand, water vapour exposure leads to a hydrated crystal phase (CH₃NH₃PbI₃·H₂O) due to the hydrophilic properties of perovskite, which is a reversible process only with dehumidification.14 Besides encapsulation of the cells, research efforts to improve long-term stability have been ongoing and are highlighted by interface modification with UV filtering caesium bromide (CsBr),15 modification of the composition of perovskite materials with the incorporation of caesium (Cs⁺) or rubidium (Rb⁺) cations in triple-cation perovskite solar cells,16,17 and engineering of interfaces with the creation of a 2D/3D perovskite combination which improves the stability and performance of the solar cell over more than one year without any loss in efficiency.18

The other bottleneck for real uptake in the market is the instability of the hole transporting material (HTM), to which doping-induced degradation of charge selective layers may contribute significantly, while other important key factors are the hygroscopic nature of HTMs, pinholes in the film morphology, humidity and thermally induced instability, interfacial degradation at the HTM/Au interface and undesirable chemical interactions of the HTM with the perovskite layer.19,20 In particular, wide bandgap HTMs such as spiro-OMeTAD typically require doping in order to achieve the necessary electrical conductivity, and the use of additives is problematic, since the hygroscopic nature of dopants makes the hole transporting layer highly hydrophilic leading to chemical degradation and negatively influences the stability of the entire device.21 One promising method to stabilize perovskite solar cells could be the appropriate choice of dopant-free and highly hydrophobic hole transporting materials, acting as a protective layer against moisture and preventing diffusion into the perovskite layer. Beside this, the hygroscopic nature of HTMs can be partially limited by device encapsulation. 10 One of the possible solutions for thermal instability is using thermally and chemically stable metal-organic complexes. Due to their excellent hole transport properties, metal-organic complex HTMs have been incorporated into perovskite solar cells, but high PCE has not been achieved.

Another approach to enhance the stability is through interface engineering of HTMs. Introducing a thin (10 nm) chromium (Cr) layer between the spiro-MeOTAD and the top gold electrode reduced the dramatic device degradation associated with increased temperature. Basically, the addition of the Cr layer prevents gold migration through the HTM to the perovskite layer.22 Besides, it has been revealed that an integrated Al₂O₃ mesoporous buffer layer in the HTM prevents the metal electrode migration that occurs during the aging process and eliminates pin-hole induced instability of HTMs by protecting the perovskite layer.23 Despite promising research results obtained in a short period of time, the researchers of perovskite solar cells still have a keen interest in enhancing the long-term stability of HTMs to achieve a lasting solution.

Another key factor that plays a major role in the commercialization potential is the cost-ineffectiveness of HTMs. To date, spiro-OMeTAD and PTAA are the hole transporting Chemical Science Minireview

materials of choice routinely employed in order to maintain the highest efficiency; however, their prohibitively high price hinders progress towards low-cost perovskite solar cell manufacturing and may contribute to more than 30% of the overall module price. The reason lies in the complicated multistep synthetic procedure, which is affordable for small quantities but is hardly scalable.

Architectures and operating mechanism

Hybrid lead halide perovskites can cumulate the function of light absorption with n- and p-type conduction. 24,25 This ambipolar charge transport property of perovskite makes the design of PSCs quite versatile. The common device architectures are composed of five layers, which allows several combinations of materials: a transparent electrode, an n-type semiconducting electron transporting material (ETM), photoactive perovskite, a p-type semiconducting hole transporting material (HTM) and a metallic electrode. Depending on the structure of the n-type layer, PSCs can be classified into mesoscopic or planar heterojunction structures,26,27 which can both be further divided into two categories based on the position of the p-type and n-type selective contact materials. The solar cells could thus be considered n-i-p (conventional) and p-i-n (inverted) structures,28-30 where the perovskite is an intrinsic semiconductor, and light enters through the n-type or the p-type layer, resulting in four different device architectures. Although inverted perovskite devices typically have higher stability with hysteresis-free behavior, conventional devices have been demonstrated to be superior in terms of power conversion efficiency. Moreover, since the perovskites have been proved to be ambipolar semiconductors, device architectures of PSCs that employ only one

of the two charge selective contacts, such as ETM-free or HTM-free PSCs, have been demonstrated.^{18,31-33} However, these typically fail to produce high PCE, and therefore it is generally agreed that both the electron and hole selective contact materials are vital to achieve high performance in PSCs.

To date, the mesoscopic n-i-p and inverted p-i-n PSC device configurations have shown the highest performance reaching over 22%. In conventional mesoscopic architectures, the glass transparent electrode fluorine-doped tin oxide (FTO) is typically coated with a compact electron transporting layer (ETL) made from TiO₂ and the additional mesoscopic TiO₂ scaffold is used on top, following by infiltration with a photoactive perovskite material. A hole transporting layer (HTL) is deposited on top of the perovskite, followed by evaporation of a metallic top electrode, usually made of a high work function metal, such as gold, whereas the inverted planar architecture has swapped charge selective contacts as shown in Fig. 1a.³⁴⁻³⁸

The simplified operating mechanism and key charge-transfer processes of the typical PSCs are shown in Fig. 1b. Incident photons excite the perovskite light harvesting layer through the transparent electrode, leading to the photogeneration of electron-hole pairs in the material. Electrons are separated (1) from the holes and injected (2) into the conduction band (CB) of the electron transporting material before migrating to the anode. Meanwhile, the holes generated in the perovskite are transferred (3) to the HOMO level of the hole transporting material, before injection of the hole into the cathode. Electron and hole injections occur quite efficiently due to the high diffusion lengths of charge carriers. Undesirable charge transfer (CT) processes such as back CT recombination of the charge carriers at three ETM/perovskite/HTM interfaces

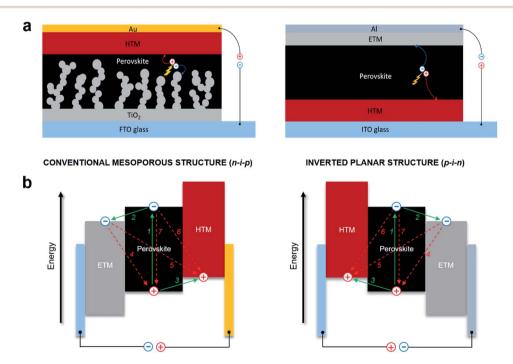


Fig. 1 (a) Structure of conventional mesoscopic n-i-p and inverted planar p-i-n device configurations; (b) schematic illustration of energy levels and charge-transfer processes in different PSC architectures.

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also occur (4–6), including non-radiative recombination (7). In the meantime, it is expected that the kinetic processes of intrinsic radiative recombination, contact characteristics of the electrode, greatly carriers greatly control the limit of photovoltaic conversion efficiency of the perovskite devices.

Hole transporting layer

HTMs are important active materials in PSCs, responsible for efficient hole extraction at the perovskite/HTM interface and prevention of undesirable charge recombination processes, leading to improvement in the performance of the device. For efficient device operation, well-aligned energy levels of the HTM with those of perovskite are crucial: the HOMO level must be less negative than that of perovskite for efficient hole injection, while the high-lying LUMO level will ensure low electron affinity enabling beneficial electron blocking properties. An ideal HTM candidate should also have high hole mobility to reduce losses during hole transport to the contact, as well as sufficient conductivity. The HTM has to be well soluble and should not require strong polar and protic solvents, as such solvents may dissolve the perovskite layer. Furthermore, since perovskites are known to be sensitive to moisture and oxygen, the hole transporting layer should act as protection against air and prevent the diffusion of external moieties; therefore high thermal and photochemical stability, as well as high hydrophobicity, are desirable properties of HTMs to resist degradation and ensure long-term durable PV operation. On the other hand, to ensure low-cost perovskite solar cell manufacturing, an ideal HTM candidate has to be easily affordable by simple synthetic schemes with a minimized number of steps and easy workup and purification procedures for cost-effective upscaling (Fig. 2).

A huge research interest directed at new HTM candidates has been devoted to gaining a better understanding of the relationship between the HTM and PSC performance. A large number and different types of HTMs have been reported so far, based on their organic^{40–54} and inorganic^{55–58} nature, of which organic HTMs can be further divided into small-molecules and conducting polymers.

To date, spiro-OMeTAD and PTAA are the hole transporting materials of choice routinely employed in order to maintain the highest efficiency; however, their prohibitively high price



Fig. 2 Schematic representation of summarized HTM properties required for PSCs in an ideal case.

hinders progress towards low-cost perovskite solar cell manufacturing and may contribute to more than 30% of the overall module price. The reason lies in the complicated multistep synthetic procedure, which is affordable for small quantities but is hardly scalable. Another key factor that plays a major role in the commercialization potential is the stability of the device. Additionally, wide bandgap hole transporting materials typically require doping in order to achieve the necessary electrical conductivity and the use of additives is problematic, since the hygroscopic nature of dopants makes the hole transporting layer highly hydrophilic leading to chemical degradation and negatively influences the stability of the entire device. One promising method to stabilize perovskite solar cells could be the appropriate choice of dopant-free and highly hydrophobic hole transporting materials, acting as a protective layer against moisture and preventing diffusion of external moieties.

Since the first report as a HTM in ssDSSCs two decades ago, ⁵⁹ the organic p-type semiconductor 2,2',7,7'-tetrakis-(N,N'-di-p-methoxyphenylamine)-9,9'-spirobifluorene (spiro-OMeTAD) is still dominating the field and has been selected as the benchmark HTM to achieve high PCE values for PSCs. Spiro-OMeTAD has a HOMO level around -5.1 eV, exhibits a hole mobility in the range of 10^{-5} to 10^{-4} cm 2 V $^{-1}$ s $^{-1}$ and has high solubility in organic solvents such as toluene or chlorobenzene, giving almost colorless thin films. However, the tedious multi-step synthesis of spiro-OMeTAD makes it prohibitively expensive and cost-ineffective. Typically, high-purity sublimation-grade spiro-OMeTAD is required to obtain high-performance devices. Moreover, it has been demonstrated to be a limiting factor for the long-term stability of the device (Fig. 3). ⁶⁰

Among the polymers, triphenylamine-based poly[bis(4-phenyl)(2,4,6-trimethylphenyl)amine] (PTAA) is the most efficient and holds the world record so far.^{61,62} The superior performance of PTAA arises from the exceptional hole mobility $(10^{-3} \text{ to } 10^{-2} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1})$. However, it is extremely expensive reaching a price of ~2000 \$ per g.

Among the inorganic hole conductors, only very few examples achieving high efficiency have been shown in the literature. Due to the limited choice of suitable materials, inorganic HTMs remain quite an unexplored alternative to the organic ones. The

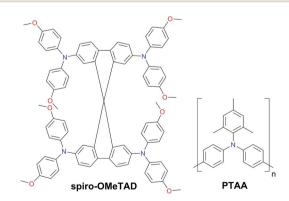


Fig. 3 Chemical structures of 2,2',7,7'-tetrakis-(N,N'-di-p-methox-yphenylamine)-9,9'-spirobifluorene (spiro-OMeTAD) and poly[bis(4-phenyl)(2,4,6-trimethylphenyl)amine] (PTAA).

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three most interesting examples of this class are copper thiocvanate (CuSCN), copper gallium oxide (CuGaO₂), and copper chromium oxide (CuCrO2). These wide bandgap semiconductors have high conductivity, suitable energy levels and good transparency. CuSCN has been studied by several research groups allowing improvement of the device performance from 12.4% to the very recent achievement over 20%.63-66 CuSCNbased devices also demonstrate improved stability under dry air and thermal annealing. Solution-processed delafossite phase CuGaO2 nanoplates were employed as the hole transporting layer yielding devices with an efficiency of 18.5% and significantly improved long-term ambient stability.⁶⁷ Recently, low-temperature solution-processed CuCrO2 nanocrystals have been demonstrated to be an effective HTL in inverted PSCs leading to 19.0% PCE with a significant improvement of device photostability.68

Chemical doping

Chemical doping is an important method in organic electronics to enhance device efficiency by controlling the energy levels, increasing the conductivity, and reducing ohmic losses in charge transport layers and injection barriers at the interface with the electrodes.^{69,70} The basic principle of p-doping in organic semiconductors is that additional mobile charge carriers are generated by electron acceptors, which remove electrons from the HOMO to generate holes of an intrinsic HTM (Fig. 4).^{71,72}

The introduction of additional charge carriers leads to an increased charge carrier density in the organic semiconductor, resulting in higher conductivity. The key requirement for an efficient doping process is the suitable electron affinity of the dopant with respect to the energy levels of an organic semiconductor.

Traditionally, the hole transporting layer of PSCs is heavily doped with p-type dopants to provide the necessary electrical conductivity for the state-of-the-art spiro-OMeTAD and other wide bandgap HTMs. Numerous p-type dopants have been developed and realized including 2,3,5,6-tetrafluoro-7,7,8,8-tetracyanoquinodimethane (F4TCNQ),⁷³⁻⁷⁵ benzoyl peroxide,⁷⁶ and copper(II)⁷⁷ and cobalt(III)^{78,79} complexes (Fig. 5). To date, the combination of second generation cobalt complex-based tris(2-(1*H*-pyrazol-1-yl)-4-*tert*-butylpyridine)cobalt(III) tri[bis(trifluoromethane)sulfonimide] (FK209)⁸⁰ and lithium bis(trifluoromethanesulfonyl)imide (LiTFSI) with an additive of 4-*tert*-

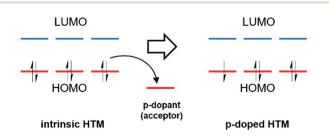


Fig. 4 Schematic illustration of the molecular p-type doping mechanism, where the dopant is an acceptor.



Fig. 5 Chemical structures of different p-type dopants for HTMs employed in PSCs.

butylpyridine (tBP) as the morphology controller is routinely employed to improve the conductivity of HTMs (Fig. 6a and b). ^{81–86} Very recently, incorporation of ZnTFSI₂ as a dopant showed increased hole mobility and long-term operational stability. ⁸⁷

On the other hand, the use of dopants is problematic and can cause several stability problems due to the sophisticated oxidation procedure and undesired ion migration. Furthermore, the hygroscopic nature of LiTFSI makes the HTL highly

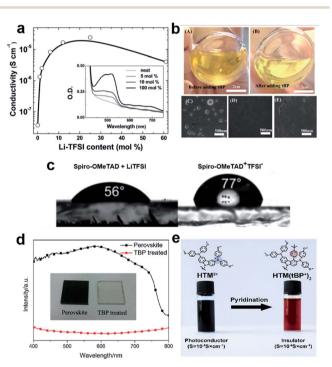


Fig. 6 (a) Effective spiro-OMeTAD conductivity and UV-vis absorption spectra (inset) as a function of the LiTFSI content. These films were left for 78 hours in air before measurement. The solid-line is simply to aid the eye. Reprinted with permission from ref. 86. (b) Photographs of a HTL solution used for spin coating. (A) Before adding tBP and (B) after adding tBP. Top-view SEM images of the freshly prepared HTL (C) without tBP, (D) with tBP, and (E) with tBP after overnight vacuum treatment (10^{-4} Pa). Reprinted with permission from ref. 85. (c) Contact angle measurements of water droplets on films of spiro-OMeTAD doped with LiTFSI and spiro-OMeTAD+TFSI- salt. Reprinted with permission from ref. 88. (d) UV-vis spectra of a TiO₂/perovskite film and tBP-treated film, a photo of the films is shown in the inset. Reprinted with permission from ref. 90. (e) Schematic representation of the chemical reaction of the hole transporting material with tBP which occurs during the doping procedure resulting in new products with different properties. Reprinted with permission from ref. 91.

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hydrophilic showing a tendency towards chemical degradation, negatively influencing the stability of the entire device (Fig. 6c).88,89 Moreover, tBP has been revealed to interact with perovskite and may dissolve it, inducing a corrosion phenomenon, and may even cause a chemical reaction with the HTM (Fig. 6d and e).90,91

Molecular doped HTMs

It is worth noting that reports on the first novel hole transporting materials for perovskite solar cells started to be published in 2014, about a year after perovskite photovoltaic research began. One has to understand that the knowledge at that time was completely different from that of the present time in 2019, resulting in sluggish progress in the beginning. However, during a span of five years, around 400 HTM-based articles were reported, including inorganic and organic molecular and polymeric materials. It would be futile to list all the compounds individually because new ones are being published each month and only a fraction shows a promising performance of at least 18%. Therefore, in this review, only the flagship HTMs will be reviewed, which have exhibited the highest performance so far. Summarized photovoltaic parameters of champion devices are listed in Table 1.

As mentioned, spiro-OMeTAD is still dominating the field and despite its high price (\sim 350 \$ per g) it is routinely employed as a highly efficient reference material for research. This is mainly because it is widely available and well-studied since it was commercialized decades ago. However, the potential for practical applications of spiro-OMeTAD is hardly possible. Therefore, huge research interest directed at new HTM candidates has been devoted to finding an ideal HTM which would be easily scalable at a reasonable cost as well as for a better understanding of the relationship between the HTM structure and PSC performance.

As a result of the success of spiro-OMeTAD, many research groups have focused on spiro-type compounds and tried to improve the PCE with slight structural modifications.92 Some representative examples of these modifications are shown in Fig. 7. Xu et al. have reported X60, where the spirobifluorene central core is replaced by spiro[fluorene-9,9'-xanthene] (SFX), which is synthesized by a one-pot approach condensing 4-bromophenol and 2,7-dibromo-9-fluorenone as the starting materials. This allowed reduction of the price of the final product by thirty times compared with that of spiro-OMeTAD. Moreover, the insertion of oxygen bridge into the structure leads to improved hole mobility and a device performance of 19.8%.93 Very recently, Chiykowski et al. judiciously studied redox and thermal properties of SFX-based HTMs bearing TPA groups. It was determined that TPA groups positioned about the conjugated fluorene moiety increase the free energy change for holeextraction from the perovskite layer, while TPAs about the xanthene unit govern the T_g values and hole mobility. 4-fold HTM-FX and HTM-FX' exhibited PCEs of 19.5% and 20.8%, respectively. 94 Recently, the fluorene-terminated spiro-OMeTAD alternative DM has been reported to have achieved a record efficiency of 23.2% so far. Such a high PCE is achieved by the

careful optimization of different amounts of additives (LiTFSI and tBP) in the HTL. Without additives, or with only small amounts of additives, the PCE of the device is very low because the conductivity of **DM** is not high enough. An encapsulated device using DM retained 92.6% of its initial PCE value after 310 h under continuous illumination conditions demonstrating its enhanced thermal stability compared with that of spiro-OMeTAD (Fig. 8a-c).95

Two-fold dimethoxydiphenylamine-substituted X59 was reported a few months later, with an identical device performance to that of its predecessor X60 and almost no hysteretic behavior,96 showing that diphenylamine units on xanthene do not play a major role; therefore it was further functionalized with covalently linked differently substituted pyridine groups. This allowed realization of tBP-free PSCs with improved stability compared with that of spiro-OMeTAD-based solar cells that contained tBP as an additive.97 Para-position substituted pyridine-based XPP showed the highest performance of 19.5% among the series, due to the fact that both nitrogen atoms in XPP can easily form strong chemical bonds with Pb atoms, while the ortho- and meta-anchored molecules can only contribute one nitrogen atom for binding to Pb. However, the pyridine anchors slightly lowered the performance when compared with X59. Another interesting strategy to improve hole transfer at the HTM/perovskite interface was demonstrated employing FDT as the HTM, where the cyclopenta [2,1-b:3,4-b']dithiophene moiety acts as an anchor to reveal an additional thiophene-iodine interaction.98 This led to one of the highest reported device performances so far of 20.2% with a J_{SC} of 22.4 mA cm $^{-2}$, $V_{\rm OC}$ of 1.15 V and FF of 0.76. C–N linked spiro structures were reported in order to investigate unsymmetrical spiro configurations, consisting of phenylpyrazole and different heteroaromatic fragments.99 S-bridged PPyra-TXA showed the highest PCE of 18.06% among the reported series.

Zhang et al. further studied X-series molecules based on the SFX core. Very recently, they reported X26 and X36 molecules, which could be considered as differently connected dimers of X59. Connection through one of the nitrogen atoms in the diphenylamine unit led to X26, while connecting through one of the phenyl rings in diphenylamine yielded X36. The PSCs based on X26 showed a remarkable power conversion efficiency of 20.2% in comparison to the 18.9% for X36-based devices, respectively. It was found that X26 forms a homogeneous capping layer, with efficient interfacial hole transfer and fast charge collection, leading to the improved $V_{\rm OC}$ and $J_{\rm SC}$ of the device, when compared with X36.100 Furthermore, replacing one of phenyl rings in both diphenylamine arms with the SFX core gave the trimer X55 with excellent 3D structured configuration.101 PSC devices with X55 as the HTM showed an impressive PCE of 20.8%, with a J_{SC} of 23.4 mA cm⁻², V_{OC} of 1.15 V and FF of 0.77. Correspondingly, the efficient charge collection in X55based devices can be related to fast hole transport and interfacial hole transfer, which also explains their high FF and J_{SC} . After aging for 6 months, the efficiency of the X55-based devices decreased by only 7% (from 20.8% to 19.3%), whereas the efficiency of the spiro-OMeTAD-based solar cells decreased by 10% (from 18.8% to 16.9%). The high uniformity and homogeneity

Table 1 Photovoltaic performance of the perovskite devices employed with the best performing doped small molecule-based HTMs sorted by PCE of the champion device

ID	$J_{ m sc}~({ m mA~cm}^{-2})$	V _{oc} (V)	FF	PCE (%)	Ref. PCE^a (%)	Lit. ref.
KR216	22.3	1.023	0.77	17.8	18.4	108
V950	22.5	1.07	0.74	17.8	18.6	120
LD29	22.02	1.11	0.75	18.04	18.25	129
PPyra-TXA ^d	20.6	1.10	0.797	18.06	16.15	99
TTPA-DBQT	22.23	1.09	0.744	18.08	17.96	148
TTPA-BDT	23.0	1.07	0.736	18.1	17.7	145
АТТ-ОМе	21.75	1.07	0.781	18.13	17.80	146
H16	23.28	1.108	0.704	18.16	18.27	131
BTT-5	22.50	1.10	0.733	18.17	18.9	143
BTF-1	21.31	1.106	0.772	18.2	18.0	144
BTT-3	21.9	1.065	0.767	18.2	18.1	142
dly-2	23.24	1.039	0.755	18.23	19.59	115
V1050 ^d	22.0	1.05	0.795	18.3	18.9	119
KR131	20.7	1.145	0.77	18.3	17.9	122
CZ-TA ^d	21.66	1.044	0.81	18.32	18.28	125
HL-2	21.30	1.09	0.79	18.34	18.77	126
V885	22.09	1.107	0.757	18.45	18.79	118
Dispiro-OBuTAD ^d	22.79	1.08	0.75	18.46	17.82	104
F33 ^d	21.01	1.11	0.79	18.48	16.26	114
EH44 ^e	21.71	1.091	0.779	18.5	19.6	128
BTSe-1 JY6 ^d	21.88	1.065	0.795	18.5	18.0	144
	21.39	1.066	0.81	18.54	16.24	113
Spiro-I	24.67	1.06	0.71	18.57	19.17	102
V1056	22.1	1.07	0.79	18.7	20.2	121
TTA3	22.18	1.153	0.733	18.76	18.77	147
\mathbf{NDT}^d	23.47	1.11	0.74	18.78	18.05	130
CuPc	22.6	1.07	0.775	18.8	20.5	141
P_{Zn} -2FTPA ^d	22.21	1.125	0.754	18.85	19.23	139
V911	22.4	1.103	0.763	18.86	18.79	118
SGT-405	22.93	1.046	0.786	18.87	17.71	111
X36	23.7	1.06	0.76	18.9	18.34	100
V885	22.43	1.104	0.764	18.92	18.79	118
BTT-4	23.04	1.090	0.753	18.97	18.9	143
Si-OMeTPA ^b	23.08	1.07	0.771	19.06	17.47	107
Z30	23.53	1.114	0.73	19.17	19.66	134
KR374	23.15	1.092	0.762	19.26	19.54	110
Ру-ОМе	22.82	1.11	0.761	19.28	18.57	116
POZ10	23.1	1.1	0.762	19.4	19.7	136
AZ2	22.94	1.14	0.746	19.4	19.1	132
DDOF	22.37	1.101	0.79	19.4	18.8	105
WT3	22.6	1.095	0.785	19.44	18.62	140
V859	23.3	1.120	0.75	19.47	18.25	137
$HTM ext{-}FX^d$	_	_	_	19.5	20.4	94
$\mathbf{XPP}^{c,d}$	23.18	1.12	0.75	19.5	16.5	97
P1	23.184	1.118	0.761	19.8	19.9	138
H11	24.2	1.150	0.71	19.8	18.9	109
X59	23.4	1.13	0.73	19.8	20.8	96
IDIDF	23.6	1.06	0.792	19.8	16.8	124
X60	24.2	1.14	0.71	19.84	_	93
V862	22.5	1.139	0.77	19.96	18.25	137
Z26	23.59	1.132	0.75	20.1	20.6	133
SCZF-5 ^d	24.40	1.11	0.74	20.1	19.11	103
V1091 ^d	22.5	1.11	0.81	20.2	20.2	121
FDT	22.7	1.148	0.76	20.2	19.7	98
$\mathbf{G2}^d$	23.52	1.146	0.76	20.2	19.25	106
G2 X26	23.52					100
		1.11	0.75	20.2	18.34	
EDOT-Amide-TPA ^d TAT- ^t BuSty ^d	22.7 22.1	1.16 1.15	0.77 0.8	20.3 20.3	19.7 20.3	135 123

Table 1 (Contd.)

ID	$J_{ m sc}~({ m mA~cm^{-2}})$	$V_{\rm oc}$ (V)	FF	PCE (%)	Ref. PCE^{a} (%)	Lit. ref.
HTM-FX' ^d	_	_	_	20.8	20.4	94
X55	23.4	1.15	0.77	20.8	18.8	101
DM	24.91	1.144	0.812	23.2	21.3	95

^a Spiro-OMeTAD or PTAA was used as the reference in most of the cases. ^b p-i-n device architecture. ^c tBP-free composition. ^d Planar device architecture. ^e LiTFSI-free composition.

of the **X55** film coverage on top of the perovskite material is a possible explanation for the good stability results (Fig. 8d and e). Remarkable performance and simplified synthetic schemes make **X60** and **X55** very promising HTM candidates for large-scale industrial production. A spirobisindane core was utilized to prepare **Spiro-I** in order to decrease the molecular symmetry of the spiro unit. This feature effectively suppresses the crystallization trend of **Spiro-I** resulting in uniform pinhole-free films with high morphological stability and a performance of 18.57% PCE. ¹⁰²

Very recently, Zhu and co-workers reported a novel design incorporating carbazole into the spiro core. A carbazole-based single-spiro-HTM named SCZF-5 achieved a PCE of 20.1%.¹⁰³ Another example, **Dispiro-OBuTAD** based on rigid ladder-type structured dispiro[9*H*-fluorene-9,6′(12′*H*)-indeno[1,2-*b*]fluorene-12′,9″-[9*H*]fluorene] with tetrakis[*N*,*N*-di(4-butoxyphenyl) amino] groups as peripheral substituents showed great steric hindrance with reduced molecular symmetry and a PCE of 18.46%.¹⁰⁴ A 3D structured dispiro-oxepine derivative **DDOF** was designed using a 3-step synthetic route and showed a PCE of 19.4% with improved long-term stability compared with spiro-

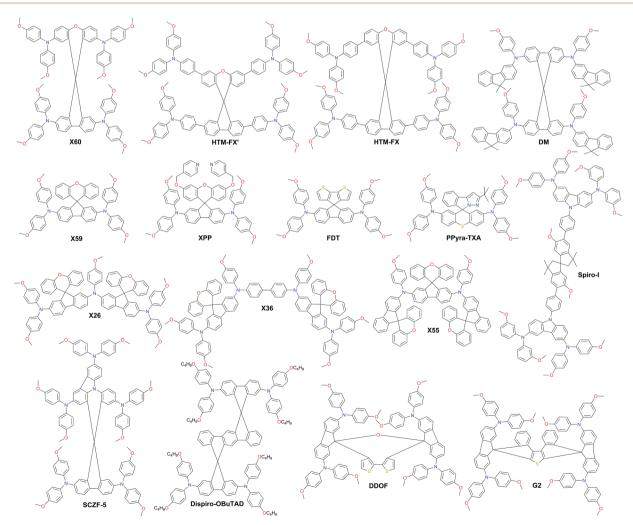


Fig. 7 Chemical structures of best-performing spiro-based HTMs.

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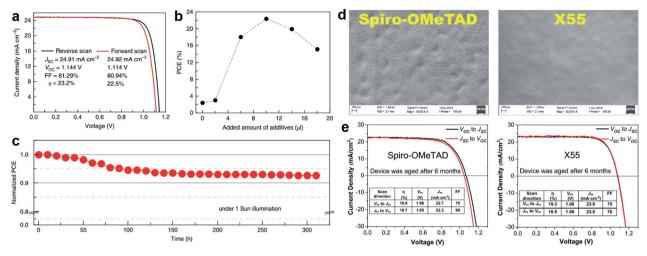


Fig. 8 (a) J-V curves measured by reverse and forward scans of the best cell using DM with active area of 0.0939 cm²; (b) relationship between the power conversion efficiency and the amount of additive added to DM. The added amount of additives indicates the sum amount of LiTFSI solution in acetonitrile (340 mg ml⁻¹) and pure tBP with a 1:1 volume ratio; (c) evolution of normalized power conversion efficiency obtained from a DM-based device with encapsulation under maximum power point tracking and continuous light irradiation (AM 1.5 G, 100 mW cm⁻², white LED) at 25 °C. Initial efficiency is 20.8% with a J_{SC} of 24.3 mA cm⁻², a V_{OC} of 1.11 V and a FF of 76.8%, which were measured from the J-Vcurves. Reprinted with permission from ref. 95. (d) Scanning electron microscopy (SEM) images of the HTM layer (top view); (e) J-V characteristics of spiro-OMeTAD and X55 based PSCs under different scan conditions after aging for 6 months. Reprinted with permission from ref. 101.

OMeTAD. 105 A similar thiophene-based dispiro functionality G2 has been reported to achieve an efficiency of 20.2%. 106

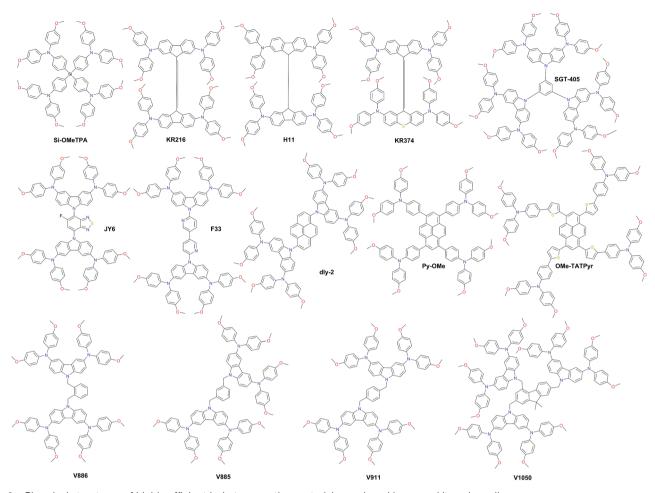
Very recently, the silicon core X-shaped molecule Si-OMeTPA has been reported to achieve a PCE of 19%.107 This novel design also offers a facile two-step synthesis process. The 9,9'bifluorenylidene-based hole-transporting material KR216, obtained by a straightforward two-step synthetic route was reported, and it mimics the synthetically challenging 9,9'spirobifluorene moiety.108 The estimated price of KR216 is around 50 times lower than that of commercial spiro-OMeTAD, and it yields a comparable power conversion efficiency of 17.8%. A higher device performance of 19.8% was achieved employing another spiro-OMeTAD analog H11, where the double bond linkage between the two planar fluorene halves is replaced by a single C-C bond. 109 The impact of different atom incorporation into the KR216 structure has been studied further. Replacement of the oxygen atom with sulfur showed a significantly improved hole-drift mobility leading to enhanced photovoltaic performance and reduced hysteresis most likely owing to the improved interface between the perovskite and HTM caused by stronger Pb-S interaction, whereas oxidation of sulfur to sulfone has a negative effect on the device performance. S-bridged KR374 showed a promising performance of 19.2%. 110 Lu et al. reported carbazole-based starburst HTMs via tuning the carbazole substitution position from 2,7- to 3,6-, respectively. 3,6-substituted SGT-405 showed a slightly improved device performance of 18.9%, compared with that of 18% in the case of 2,7-substitution.¹¹¹

Carbazole derivatives have been intensively studied since they have interesting features such as the low-cost of the 9Hcarbazole starting material, good chemical and environmental stability provided by the fully aromatic unit, and easy incorporation of a wide variety of functional groups into the nitrogen

atom that allows better solubility and fine tuning of the electronic and optical properties. 112 3,6-Dimethoxydiphenylaminesubstituted carbazoles as donor units at the periphery were widely used to tune the HOMO level of the final molecule. Some representative examples of such systems are shown in Fig. 9. Wu and co-workers reported benzothiadiazole (BT)-based HTM series.113 The monofluorinated BT in JY6 increases its hole mobility, hole extraction, and hole transporting ability, and thus significantly enhances the photovoltaic performance ($\eta =$ 18.5%) compared with non-fluorinated ($\eta = 16.9\%$) and difluorinated ($\eta = 15.7\%$) analogs. The same photovoltaic performance was recently obtained with F33, where BT was replaced by 3,3'-bipyridine.114

Li et al. functionalized a two-dimensional pyrene core with two- and four-fold electron-rich substitutions. 115 18.2% PCE in planar PSCs has been achieved by employing disubstituted dly-2, which is slightly higher in comparison with that in PSCs using tetrasubstituted derivatives. Very recently, another pyrene HTM Py-OMe comprising four triarylamine substituents was reported by Cui et al. to achieve a PCE of 19.28%.116 Bridging the latter with extra thiophene units yielded OMe-TATPyr and further improved the photovoltaic performance over 20%.117 A family of branched HTMs containing two diphenylaminesubstituted carbazole fragments linked by a non-conjugated differently substituted methylenebenzene unit has been extensively studied by Getautis et al.118 ortho-, meta-, and para-dimethylenebenzene linked isomers V886, V885, and V911, respectively, were investigated recently. The performance of V885 and V911 is on a par with that of spiro-OMeTAD, reaching 18.9%, while the introduction of additional branches or substitution of methoxy groups in place of methyl did not lead to higher efficiency. A slightly lower performance of 18.3% has been achieved with V1050, where the central benzene unit is

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Chemical structures of highly efficient hole transporting materials employed in perovskite solar cells.

replaced with fluorene.119 Owing to the simplicity of synthesis for the V-family molecules it holds great promise for practical application in PSCs.

In Fig. 10, the most efficient carbazole-based HTMs are shown. The low-cost enamine V950 was synthesized via an extremely simple route from commercially available and relatively inexpensive starting reagents, resulting in more than one order of magnitude lower cost of the final product compared to the commercial spiro-OMeTAD, and showed a PCE of 17.8%. 120 Very recently, the PCE has been further improved with anilinebased enamines using the same straightforward synthetic protocol. Three diphenylethenyl moieties containing V1091 showed an excellent hole mobility of $1.7 \times 10^{-2} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ leading to a PCE of 20.2%, while V1056 showed a slightly lower performance of 18.7%.121 In one of the earliest reports, 18.3% device performance was achieved employing triazatruxenebased KR131, which exhibited surface interaction with the perovskite material resulting in efficient hole injection from the valence band of perovskite into the HOMO of the HTM, outperforming the reference spiro-OMeTAD.122 Very recently, another triazatruxene HTM TAT-^tBuSty was reported to achieve a PCE of 20.3%. 123 Cho and co-workers reported a fluorinated indolo[3,2-b]indole-based derivative IDIDF.¹²⁴ A planar π conjugated backbone linked with a flexible alkyl chain enabled the formation of a molecular stacked arrangement with strong π - π interaction, leading to improved hole mobility and a PCE of 19.8%.

The carbazole-based examples CZ-TA¹²⁵ and HL-2 ¹²⁶ showed an identical photovoltaic performance of 18.3%. From a structural point of view, both have long alkyl chains for solubility improvement, octyl and hexyl, respectively, whereas the peripheral donors are completely different. CZ-TA possesses 1,3,6,8-substituted p-dimethoxytriphenylamine units, while HL-2 is 2,7-substituted with o,p-dimethoxyphenyl-extended diphenylamine units. Very recently, a significantly enhanced photovoltaic performance of 19.85% and device stability have been realized by adding 10 wt% of the sister molecule methylthiosubstituted CZ-STA to CZ-TA as a blend HTL.127 A simple dimethoxydiphenylamine substituted N-ethylhexyl carbazole HTM EH44 was recently reported to achieve 18.5% PCE with 1000 hour operational stability due to HTM oxidation by AgTFSI.128 The star-shaped carbazole derivative LD29 has three OMe-TPA units. The simple design of LD29 gave a performance of 18.04%.129

Fused thiophene rings are attractive candidates as building blocks for HTM synthesis due to better π -conjugation across the molecule; some of the most efficient examples are shown in Fig. 10. A naphtho[1,2-b:4,3-b']dithiophene-based HTM, NDT,

VVW VVIET VV

Fig. 10 Chemical structures of hole transporting materials employed in high performance perovskite solar cells

has been reported by Cui and co-workers and showed a PCE of 18.8%. 130 Another similar example employing the dithieno [3,2b:2',3'-d|pyrrole derivative H16 was reported to achieve a PCE over 18%.131 Replacing methoxy groups on TPA with methyls improved the molecular stacking and led to a significantly higher performance of 19.4% achieved with AZ2 by Zheng and co-workers. 132 Very recently, Zhang and co-workers reported two HTMs with the introduction of vinylene bridges between the central core and electron-rich triarylamine donating units through the Wittig reaction, denoted as Z26 and Z30. Thiophene-based **Z26** exhibited an impressive PCE of 20.1%. ¹³³ Due to the introduction of double bonds, Z26 presents a more homogeneous surface, higher hole mobility, and higher conductivity than its analog, where p-dimethoxytriphenylamine units are connected directly to the thiophene. The second one, Z30 based on phenothiazine, showed a slightly lower performance of 19.2%.134 Petrus et al. introduced an amidefunctionality in the backbone of HTMs to synthesize an EDOT-Amide-TPA material by a simple condensation reaction which showed a very high performance of 20.3%.135

Phenoxazine-based **POZ10** reported by Chen and co-workers showed a PCE of 19.4%.¹³⁶ Other very interesting branched molecules **V862** and **V859**, bearing *p*-dimethoxydiphenylamine-substituted fluorene fragments, were reported by Malinauskas *et al.* and are presented in Fig. 10.¹³⁷ They can be produced in a two-step procedure from cheap, commercially available starting reagents, and therefore are very promising for large-scale production. Furthermore, **V862** yielded a maximum PCE up to 20%, whereas **V859** showed a slightly lower value of 19.5%. A similar performance of 19.8% was obtained with the *peri*-xanthenoxanthene centered HTM **P1** reported by Xu *et al.*¹³⁸

Porphyrin derivatives have been widely studied as hole transport layers due to their electron rich characteristics. Azmi *et al.* reported Zn porphyrin-based HTMs with conjugating fluorinated triphenylamine wings. The best among the series **P**_{Zn}-2FTPA exhibited a PCE of 18.85%.¹³⁹ Chiang *et al.* designed and synthesized the dimeric porphyrin material **WT3** with a suitable HOMO level and hole mobility leading to an excellent PCE of 19.44%.¹⁴⁰ Phthalocyanine derivatives have also been successfully applied as HTMs, owing to their specific molecular

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ordering, thereby giving rise to a highly crystalline and robust stack with high hole mobility. To date, the most successful example of this class has been **CuPc**, which resulted in the highest PCE of 18.8% with outstanding long-term stability against thermal stress under an air atmosphere.¹⁴¹

HTMs based on the sulfur-rich benzotrithiophene (BTT) core were intensively studied as such fused systems are known to maximize the π -orbital overlap, inducing face-to-face π -stacking and facilitating charge transport through intermolecular hopping. Star-shaped BTT-3 was first reported with an optimized HOMO level, showing an excellent band alignment with the perovskite, leading to a PCE of 18.2%. 142 Encouraged by this result, Garcia-Benito et al. have further studied the impact of isomerism on BTT-based HTMs.143 It was found that cis arrangement of the sulfur atoms facing each other in the core of BTT-4 may further benefit the interaction with the perovskite, leading to an impressive PCE of 19%, while the 4-fold isomeric form of BTT-5 showed 18.2% PCE. Very recently, the heteroatom effect (N, O, and Se) was studied yielding benzotripyrrole (BTP), benzotrifuran (BTF), and benzotriselenophene (BTSe) central cores, respectively. From single-crystal diffraction, it was found that BTF-1 shows tighter molecular π - π interactions than BTT-3 and BTSe-1. However, the best PSC performance of 18.5% was

achieved with BTSe-1, while BTF-1 showed a slightly lower result of 18.2%.144 Benzodithiophene (BDT) and the more extended sulfur-rich core anthratetrathiophene (ATT) were also used as scaffolds for novel HTMs. Sandoval-Torrientes et al. reported TTPA-BDT¹⁴⁵ molecule with four-fold substitution bringing the performance ($\eta = 18.1\%$) close to that of BTT analogs. A similar PCE was achieved with devices prepared with the anthratetrathiophene-based ATT-OMe, which showed the highest efficiency of 18.13% among a series of different alkoxy length HTMs, showing that longer alkoxy chains are not beneficial. 146 Introduction of extra thiophene rings between the ATT central core and triarylamine yielded TTA3 and led to an increased PCE of 18.7%.147 Further engineering of the ATT scaffold led to dibenzoquinquethiophene (DBQT), where the central benzene ring is replaced with thiophene. However, the PCE of TTPA-DBQT HTM remained almost identical to that of ATT-OMe reaching 18.08% (Fig. 11).148

In conclusion, tremendous effort has been made to develop new alternative low-cost and efficient HTMs to replace spiro-OMeTAD, and organic small-molecule HTMs are the most widely developed group in PSCs owing to their synthetic variety, tuneable properties, high purity, and simple solution processing. However, although the performance of PSCs is dramatically

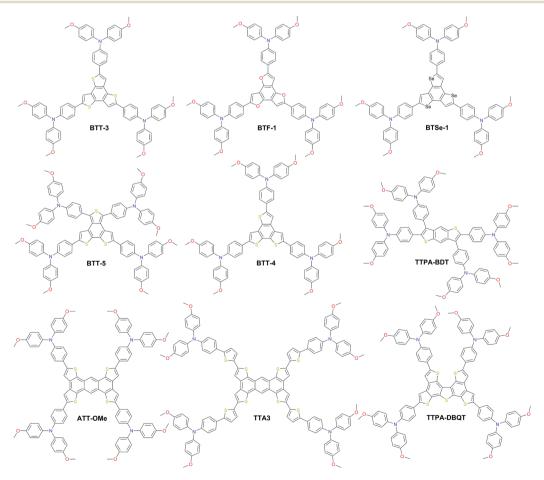


Fig. 11 Chemical structures of the most efficient hole transporting materials based on benzodithiophene (BDT), benzotrithiophene (BTT), benzotrifuran (BTF), benzotriselenophene (BTSe), anthratetrathiophene (ATT), and dibenzoquinquethiophene (DBQT) cores.

enhanced, most of the reported high-efficiency doped HTMs suffer from rapid degradation and are limited by a very short operation lifetime of up to a few months.

Molecular dopant-free HTMs

A promising solution for stabilizing PSCs is the appropriate choice of dopant-free HTMs. However, the PCEs of pristine HTL devices consistently lie around 15% with only very few examples over 18% (Fig. 12 and Table 2). The long-term stability of PSCs is one of the critical issues that need to be addressed for their commercial application. Removing the dopants has already been demonstrated to be very effective towards improved device stability.

Huang *et al.* presented a dopant-free truxene-based HTM decorated with three diarylamine groups and six hexyl side chains, adopting a planar, rigid, and fully conjugated molecular geometry. PSCs fabricated with a p-i-n architecture using **Trux-OMeTAD** showed a high PCE of 18.6% with minimal hysteresis. ¹⁴⁹ The anthanthrone dye based molecule **TPA-ANT-TPA** has been reported by Pham *et al.* to achieve 17.5% PCE using no regular doping. ¹⁵⁰ Hazmi *et al.* reported dopant-free molecules based on dibenzothienopyrrole combined with diphenylamine donors tuned with differently positioned methoxy groups. ¹⁵¹ *meta*-substituted *mDPA-DBTP* showed the highest performance among the series achieving a PCE over 18%. Notably, devices

based on dopant-free mDPA-DBTP retained 81% of its original PCE after 33 days of storage, during which the doped spiro-OMeTAD devices lost their PCE completely as shown in Fig. 13a. m-MTDATA has been reported to reach a PCE as high as 18.12% among simple solution-processed inverted PSCs with a $J_{\rm SC}$ of 22.50 mA cm $^{-2},~V_{\rm OC}$ of 1035 mV and FF of 0.778. Furthermore, m-MTDATA based devices without any encapsulation showed significantly better stability than the PEDOT:PSS based devices after 1000 h exposure to an ambient environment with a humidity of 30 RH%.152 Another commercial example TAPC has been demonstrated to be an efficient HTM in p-i-n configuration PSCs. By adopting TAPC as the HTL, the best device achieved a PCE of 18.80% with minor hysteresis and increased stability without any encapsulation.153 Li with coworkers presented a simple polycyclic 2,5,9,12-tetra(tert-butyl) diacenaphtho[1,2-b:1',2'-d]thiophene dopant-free HTM denoted as PCA-1 with a PCE of 18.17%. 154 Simple design of a TPAC3M dopant-free HTM has been reported by Park et al. 155 Fabricated p-i-n inverse type planar PSCs with the configuration ITO/ TPAC3M/CH₃NH₃PbI₃/PCBM/ZnO/Al exhibited 17.54% PCE.

Donor- π -bridge-acceptor (D- π -A) type dopant-free HTMs have great potential to show high charge carrier mobility due to strong dipolar intermolecular interactions, minimizing ohmic losses of the contact. Moreover, they combine the advantages of both small molecules, like well-defined structures, and

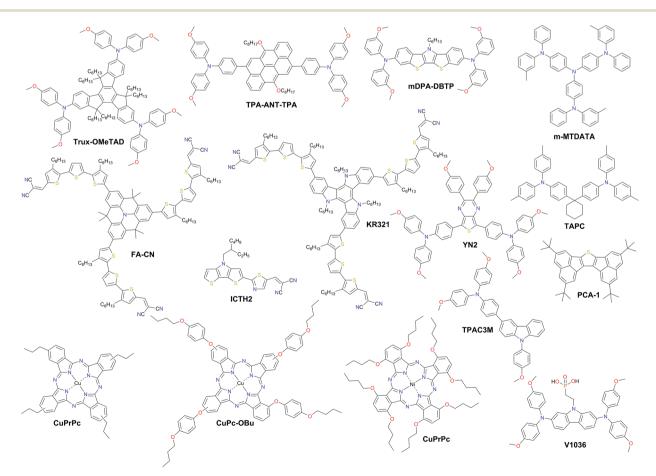


Fig. 12 Chemical structures of the most efficient dopant-free hole transporting materials applied in PSCs.

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polymers, like good thermal, electrochemical and photochemical stability, together with high solubility and suitable wetting on the perovskite. Typically, they are composed of a planar central unit inducing the formation of a molecular stacked arrangement due to strong π - π interaction linked to a strong accepting unit and combined with flexible alkyl chains leading

to improved hole mobility. Recently, a D- π -A-type HTM coded as **FA-CN** was reported, incorporating a fused quinolizino acridine donor with alkylsubstituted terthiophenes and malononitriles as acceptors. Optimized devices with dopant-free FA-CN showed an impressive PCE of 18.9% with superior long-term stability under full illumination for 1300 h (Fig. 13d). 158 Changing the quinolizino acridine central core to triazatruxene yielded the KR321 HTM with a slightly improved performance of 19% due to the highly ordered characteristic face-on organization leading to increased vertical charge carrier transport (Fig. 13c and e).157 Bharath et al. reported the D- π -A type ICTH2 HTM based on electrondonating dithieno[3,2-b:2',3'-d]pyrrole and electron-accepting dicyanovinylene moieties imparting high intramolecular charge transfer nature and eliminating the need for additives or dopants during the fabrication of solar cell devices. 159 PSCs with the ICTH2 HTM showed a PCE of 18.75% with an active area of 2.04 cm². Very recently, the D-A-D type HTM YN2 featuring triphenylamine as the donor along with a thienopyrazine unit as the acceptor has been presented by Xu et al. The YN2-based PSC affords an impressive PCE value of 19.27% with a $V_{\rm OC}$ of 1.11 V, a J_{SC} of 23.15 mA cm⁻² and a FF of 0.75 as shown in Fig. 13b. 156

Another interesting class of dopant-free HTMs is phthalocyanines (Pcs). The optical and electronic properties of these macrocycles can be easily adjusted by modifying the peripheral and non-peripheral substituents and the metal center. Pcs have unique properties, such as ease of synthesis related to low production cost, relatively high hole mobility, and high hydrophobicity, as well as excellent chemical, thermal, and photo stability. So far, the highest performance using dopant-free layers in this class has been achieved by metal phthalocyanines, such as copper(II) phthalocyanines (CuPcs) and nickel(II) phthalocyanines (NiPcs). Liu et al. reported copper(II) Pc with tetrapropyl side chain substitution denoted as CuPrPc. 160 A comprehensive study by GIXRD and AFM confirmed that the surface of the CuPrPc film grown on perovskite has low surface roughness, high quality crystallization and face-on molecular orientation enhancing hole transport leading to a PCE of 17.8%. Moreover, it has a good coverage area and high hydrophobicity, improving the stability of PSC devices. Jiang et al. found that a small structural change from butyl groups to butoxy groups in the substituents of the Pc rings significantly influences the molecular ordering and effectively improves the hole mobility and solar cell performance. The optimized PSCs employing CuPc-OBu as the dopant-free HTM afforded a PCE of 17.6%.161 In addition, PSC devices containing the dopant-free CuPc-OBu HTM also exhibited excellent stability when stored without encapsulation under ambient conditions with a RH of 85% relative to those containing doped spiro-OMeTAD, mainly due to the high moisture resistivity of the CuPc-OBu interlayer. Chen et al. reported that solution-processable nickel

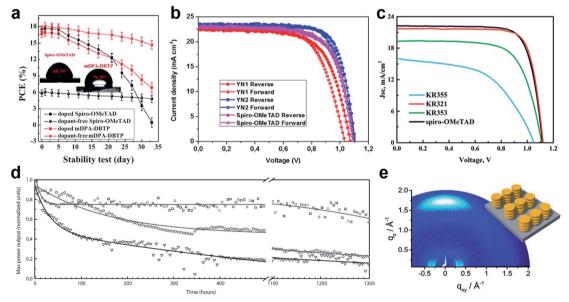


Fig. 13 (a) Performance stability of unencapsulated PSCs based on mDPA-DBTP under ambient air storage (at a humidity level of $40 \pm 5\%$ and a temperature of 25 ± 3 °C). Reprinted with permission from ref. 151. (b) J-V curves of PSCs based on the YN2 HTM. Reprinted with permission from ref. 156. (c) J-V curves of the dopant-free HTM KR321 and doped spiro-OMeTAD as the reference. Reprinted with permission from ref. 157. (d) Maximum power point tracking of perovskite solar cells prepared in a single experiment, using undoped FA-CN (\Box), TPA-CN (\odot), and doped spiro-OMeTAD (∇) as hole-transporting materials. The measurements were performed under UV-filtered simulated sunlight in an argon atmosphere. The initial power conversion efficiency was measured after storing the device under argon and in the dark for 24 h. Reprinted with permission from ref. 158. (e) GIWAXS pattern of the KR321 film coated with tetrachloroethane on a silica wafer (schematic illustration of the molecular surface arrangement). Reprinted with permission from ref. 157.

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Table 2 Photovoltaic performance of the perovskite devices employed with best performing dopant-free small molecule-based HTMs sorted by PCE of the champion device

ID	$J_{ m sc}~({ m mA~cm}^{-2})$	$V_{\rm oc}$ (V)	FF	PCE (%)	Ref. PCE^a (%)	Lit. ref.
TPA-ANT-TPA	21.07	1.03	0.796	17.5	16.8	150
$TPAC3M^b$	22.79	1.00	0.78	17.54	12.6	155
CuPc-OBu	22.8	1.06	0.73	17.6	18.8	161
\mathbf{CuPrPc}^c	23.2	1.01	0.76	17.8	17.5	160
$V1036^{b}$	21.9	1.09	0.81	17.8	19.2	163
$mDPA-DBTP^{c}$	21.13	1.12	0.76	18.09	17.82	151
m -MTDATA b	22.50	1.035	0.78	18.12	13.44	152
PCA-1 ^c	22.30	1.062	0.767	18.17	18.30	154
NiPc-(OBu) ₈	23.1	1.08	0.734	18.3	19.4	162
Trux-OMeTAD ^b	23.2	1.02	0.79	18.6	16.3	149
ICTH2	24.78	1.03	0.735	18.75	14.74	159
\mathbf{TAPC}^{b}	22.32	1.04	0.811	18.8	12.9	153
FA-CN	21.71	1.13	0.77	18.9	19.2	158
KR321	21.70	1.13	0.78	19.03	19.01	157
YN2	23.15	1.11	0.75	19.27	17.80	156

a Doped spiro-OMeTAD or PEDOT:PSS was used as the reference in most of the cases. p-i-n device architecture. Planar device architecture.

phthalocyanine (NiPc) abbreviated NiPc-(OBu)8 and vanadium (V) oxide (V₂O₅) are successfully incorporated into structured mesoporous PSCs showing a PCE of up to 18.3%.162

Magomedov et al. have demonstrated a hole-transporting self-assembled monolayer (SAM) as the dopant-free holeselective contact in p-i-n PSCs.163 SAM formation is achieved by simply immersing the substrate into a solution of a novel molecule V1036 that binds to the indium tin oxide surface due to its phosphonic anchoring group. A PCE of up to 17.8% with an average fill factor close to 80% and undetectable parasitic absorption was demonstrated. A slightly lower PCE of 17.3% was achieved by another SAM-forming molecule MC-43 having a carboxylic anchor as proposed by Yalcin et al. 164 Further gains in efficiency can be expected upon SAM optimization by means of molecular and compositional engineering.

So far, D-A type and branched structures have been proven to be two major design strategies to prepare high performance dopant-free HTMs. Such molecules enable better intermolecular interactions for the increase of the charge mobility. In general, the doping process is not required for efficient hole transport and collection if the HTM can exhibit a hole mobility as high as 10^{-4} – 10^{-3} cm² V⁻¹ s⁻¹. Further optimization of these types of HTMs will undoubtedly lead to a PCE above 20% with excellent stability.

Polymeric dopant-free HTMs

Polymers are potentially attractive HTM candidates in perovskite solar cells since they typically present good stability, processability, mechanical flexibility and film uniformity with tunable energy levels. Both high density and hydrophobicity of polymers are also very important for protecting the perovskite layer from moisture in ambient environments, therefore enhancing PSC lifetime, as discussed previously.

Three different kinds of polymers are mostly used as HTMs for perovskite solar cells including homopolymer, copolymer, and D-A copolymer types. The class of polymeric HTMs has recently been found to be very effective for highly efficient and stable PSCs and is emerging very quickly. The chemical structures of the most efficient dopant-free polymeric hole

Table 3 Photovoltaic performance of the perovskite devices employed with best performing dopant-free polymeric HTMs sorted by PCE of the champion device

ID	$J_{ m sc}~({ m mA~cm}^{-2})$	$V_{\rm oc}$ (V)	FF	PCE (%)	Ref. PCE^{a} (%)	Lit. ref.
P3CT-Na ^b	21.3	1.05	0.75	18.3	_	165
Asy-PBTBDT	22.4	1.11	0.732	18.3	18.5	169
$PTB7^c$	22.6	1.13	0.71	18.5	13	168
pDPP5T-2 ^c	21.5	1.15	0.76	18.9	13	168
PCDTBT1 ^c	22.2	1.1	0.782	19.1	19.4	171
P3CT-CH ₃ NH ₂ ^b	22.2	1.09	0.81	19.6	_	165
DTB	25.5	1.10	0.698	19.68	19.81	167
$TB(MA)^b$	23.45	1.08	0.78	19.76	16.93	166
PDBT-T1 ^c	22.2	1.17	0.77	19.8	13	168
$PTEG^c$	22.5	1.14	0.77	19.8	17.9	170
$PDCBT^{c}$	22.7	1.17	0.80	21.2	13	168

 $[^]a$ Doped spiro-OMeTAD or PTAA was used as the reference in most of the cases. b p-i-n device architecture. c Planar device architecture.

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Chemical structures of the most efficient dopant-free polymeric hole transporting materials applied in PSCs.

transporting materials applied in PSCs are listed in Fig. 14 and Table 3.

The homopolymer-based polyelectrolytes P3CT-CH₃NH₂ and P3CT-Na containing π -delocalized backbones with charged pendant groups were reported by Li et al. 165 When using P3CT-CH3NH2 to replace P3CT-Na, a much smoother film was obtained, which is important for the growth of a uniform perovskite layer on top in the inverted PSC configuration. In addition, the hole mobility is also improved in P3CT-CH₃NH₂, facilitating hole collection. By replacing P3CT-Na with P3CT-CH₃NH₂, the PCE has been greatly improved from 18.3 to 19.6%. Very recently, a similar strategy using side-chains end-capped by CH₃NH₃⁺ cations was reported by Zhang and co-workers. ¹⁶⁶ A conjugated polyelectrolyte termed TB(MA), whose backbone is composed of 2,5-dialkoxy-1,4-phenylene and thiophene units showed a very high PCE of up to 19.76% in inverted PSCs.

The edge-on alternating copolymer **DTB** with a rather simple structure composed of 2,5-dialkoxy-1,4-phenylene units and bithiophene units, where the alkoxyl side-chains are optimized endowing the polymer with both sufficient solubility in common solvents and an edge-on orientation atop perovskite was very recently reported by Zhang and co-workers. A high hole mobility of 1.0 \times 10⁻⁴ cm² V⁻¹ s⁻¹ and lamellar packing of polymer chains led to a stabilized PCE of 19.68% with an ultrahigh short-circuit current density of 25.50 mA cm⁻² (Fig. 15a and b).167

Hou et al. reported a strategy to use tantalum doped tungsten oxide (Ta-WO_x)/PDCBT conjugated polymer multilayer, which offer a surprisingly small interface barrier and form quasi-ohmic contacts leading to an impressive PCE of 21.2% combined with over 1000 hours of light stability (Fig. 15f and g).168

D-A type copolymers have been found to be very effective dopant-free HTMs as such a design strategy can ensure high hole mobility and enhanced device stability by rationally

implementing different donors and acceptors. In addition, the introduction of suitable side chains into their conjugated backbones may form two-dimensional polymers with effectively tuned morphological properties.

Lee et al. reported a D-A type copolymer asy-PBTBDT comprising benzo[1,2-b:4,5:b']dithiophene (BDT) and benzothiadiazole (BT) as donor and acceptor units, respectively. 169 Introduction of asymmetric alkoxy substituents on BT units produced irregularity within a repeating unit of the polymer resulting not only in its solubility in common organic solvents, but also in its high solubility in the green solvent 2-methylanisole, which is a known food additive. The best device employing dopant-free asy-PBTBDT achieved a PCE of 18.3%, which is equivalent to the results obtained using the best control device employing doped spiro-OMeTAD. The performance was significantly improved using another BDT and BT based copolymer PTEG as reported by Kim and co-workers. 170 Here, side chains were further engineered by introducing tetraethylene glycol (TEG) chains on BT units. TEG groups improve solubility by enhancing dipole-dipole interactions with the solvent. Moreover, flexible TEG groups can affect hole mobility by preventing backbone twisting and increasing π - π stacking. An improvement in the contact between perovskite and PTEG occurs because the surface energy of TEG groups is higher than that of alkyl groups. A dopant-free PTEG-based device achieved an impressive efficiency of 19.8% with a $J_{\rm SC}$ of 22.5 mA cm⁻², a $V_{\rm OC}$ of 1.14 V, and a FF of 0.77 in planar PSCs (Fig. 15c and d). Cai et al. reported three HTMs comprising a carbazole donor moiety flanked by two thienyl groups that are co-polymerized with a pristine or functionalized BT unit with two methoxy or octyloxy substituents, resulting in PCDTBT, PCDTBT1, and PCDTBT8.¹⁷¹ It was found that the device performance strongly depends on the chemical structure of the conjugated polymer side chains. When PCDTBT1 with two methoxy units on the BT Chemical Science Minireview

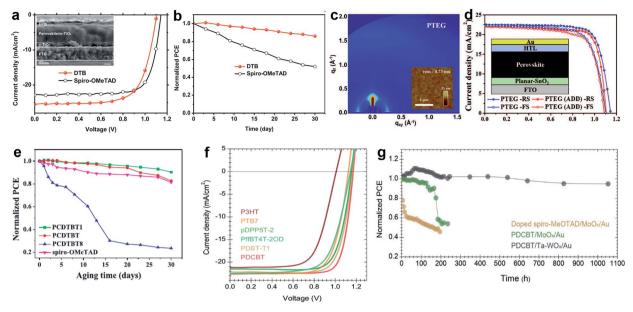


Fig. 15 (a) J-V characteristics of DTB with a cross-sectional SEM image in the inset (scale bar: 200 nm); (b) evolution of PCE in air for PSC devices based on DTB. Reprinted with permission from ref. 167. (c) Grazing-incidence wide-angle X-ray scattering (GIWAXS) and atomic force microscopy (AFM) images of PTEG; (d) J-V curves for PTEG devices (planar-SnO₂). Reprinted with permission from ref. 170. (e) The evolution of PCE for epoxy-encapsulated devices incorporating the PCDTBT1 HTM that have been stored under ambient conditions for a duration of 30 days. Reprinted with permission from ref. 171. (f) The J-V characteristics of perovskite solar cells with different polymer HTMs under AM 1.5G illumination; (g) unencapsulated device photostability tests under continuous one sun illumination in a home-built chamber filled with N₂. PCE variation of the HTM stacks based on a C_{60} -SAM with strong binding between the phosphonic acid and the oxide surface as the ETM: spiro-MeOTAD/MoO_x/Au (yellow), PDCBT/MoO_x/Au (green) and PDCBT/Ta-WO_x/Au (black). Reprinted with permission from ref. 168.

unit was employed as the dopant-free HTM, the champion device efficiency was 19.1%, while the unsubstituted and octyloxy analogues gave PCEs of only 17.1% and 15.4%, respectively. Moreover, PCDTBT1-based devices show remarkable stability, retaining 90% of their original PCEs after storage for more than 30 days. This is attributed to their hydrophobic nature compared to that of spiro-OMeTAD as shown in Fig. 15e.

Various D–A type HTMs such as PTB7, pDPP5T-2, and PDBT-T1 have also been screened for their device architecture with a Ta-WO $_x$ doped interface delivering efficiencies of 18.5%, 18.9%, and 19.8%, respectively (Fig. 15f). ¹⁶⁸

Dopant-free polymers have recently been shown to achieve both high efficiency and device stability; however, they typically suffer from a few drawbacks such as batch-to-batch reproducibility, purity, and high synthetic cost. Another hot approach lies in crosslinking of small molecule HTMs after/before deposition of the perovskite layer. In this sense, the crosslinked-HTM exhibits higher hole mobility and morphological stability, as well as enhancing hydrophobicity, protecting the perovskite layer from decomposition. The major challenge here is the exploration of suitable crosslinking chemistry and functional groups.

Conclusions and outlook

This article overviews the highest performance doped and dopant-free HTMs, selected from the HTM database, which includes over 400 publications on the inorganic and organic molecular and polymeric hole transporting materials published

until 2019. These hand-picked flagship molecules demonstrate how small changes in the molecular structure such as different atoms and different functional groups, and changes in substitution positions or the length of the π -conjugated systems can result in significant changes in the properties of the hole transporting materials and performance of perovskite solar cell devices. We divided our HTM library into three categories: molecular doped HTMs, molecular dopant-free HTMs and polymeric dopant-free HTMs. The photovoltaic performances of the champion perovskite devices of selected molecules were compared with the most common reference materials such as spiro-OMeTAD, PTAA, and PEDOT:PSS.

We note that for efficient device operation, the well-aligned energy level of HTMs with that of perovskite is crucial: the HOMO level must be less negative than that of perovskite for efficient hole injection, while the high-lying LUMO level will ensure low electron affinity enabling beneficial electron blocking properties. An ideal HTM candidate should also have high hole mobility to reduce losses during hole transport to the contact, as well as sufficient conductivity. The HTM has to be well soluble and should not require strong polar and protic solvents, as such solvents may dissolve the perovskite layer. Furthermore, since perovskites are known to be sensitive to moisture and oxygen, the hole transporting layer should act as protection against air and prevent the diffusion of external moieties; therefore high thermal and photochemical stability, as well as high hydrophobicity, are desirable properties of HTMs to resist degradation and ensure long-term operation. On the other hand, to ensure low-cost perovskite solar cell

manufacturing, an ideal HTM candidate has to be easily affordable by simple synthetic schemes with a minimized number of steps and easy workup and purification procedures for cost-effective upscaling.

The quest to design the best hole transporting molecule with well-aligned energy levels, sufficient solubility, and high hole mobility and conductivity opens the door to better-performing perovskite solar cell devices. On the other hand, while perovskite solar cells are making great strides toward commercialization, the use of highly stable hole transport molecules is crucial for the long-term stability of the overall device.

Tremendous effort has been made to develop new alternative low-cost and efficient HTMs to replace spiro-OMeTAD, and organic small-molecule HTMs are the most widely developed group in PSCs owing to their synthetic variety, tunable properties, high purity, and simple solution processing. However, most of the reported high-efficiency doped HTMs suffer from rapid decomposition and are limited by a very short operation lifetime of up to a few months due to the dopant combination of the cobalt complex (FK209) and lithium bis(tri-fluoromethanesulfonyl)imide (LiTFSI) with the additive of 4-tert-butylpyridine (tBP) as the morphology controller.

In this context, a unique solution to eliminate the negative influence of chemical dopants on the stability of the entire perovskite solar device is to utilize dopant-free HTMs. Besides the outstanding contribution to the device stability by dopant-free HTMs, these materials have become very attractive because of their improvement in terms of power conversion efficiency of perovskite devices. Two main design strategies of dopant-free HTMs have been introduced so far to achieve the highest performance. D–A type and branched structures provide better intermolecular interactions towards increased charge mobility.

A novel approach using a hole-transporting self-assembled monolayer (SAM) as the dopant-free hole-selective contact in highly efficient p-i-n PSCs has been demonstrated due to its anchoring group binding to the ITO surface. Further gains in efficiency and stability are expected with SAM optimization using molecular and compositional engineering.

Another important approach is dopant-free polymers, which has recently been shown to provide both high PCE and device stability, although there are several drawbacks: reproducibility, low purity, and high synthetic cost. Lastly, the cross-linking of small-molecule HTMs before/after deposition of the perovskite layer is a promising direction in this field. The advantage of this approach is that the crosslinked-HTM exhibits higher hole mobility and morphological stability, as well as increased hydrophobicity that may protect the perovskite layer from decomposition. However, a deeper investigation towards appropriate crosslinking chemistry and functional groups is required.

Although several reviews on HTMs have been published, progress on dopant-free HTMs needs to be reviewed and analyzed facilitating further development of molecular and polymeric dopant-free HTMs and alternative chemical approaches such as "click chemistry" inspired crosslinking and self-assembled monolayer formation for the inevitable

replacement of doped spiro-OMeTAD. We hope that this minireview cataloging the library of the most efficient molecules will be of use to the community and help to develop solutions for more efficient and innovative compounds.

Conflicts of interest

There are no conflicts to declare.

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